Panasonic

MOS FET FCAB22370L1

FCAB22370L1

Gate resistor installed Dual N-channel MOS FET

For lithium-ion secondary battery protection circuits

Features

- Low source-source ON resistance:Rss(on) typ. = 3.3 m Ω (VGS = 3.8 V)
- CSP(Chip Size Package)
- RoHS compliant (EU RoHS / MSL:Level 1 compliant)
- Marking Symbol: 3P

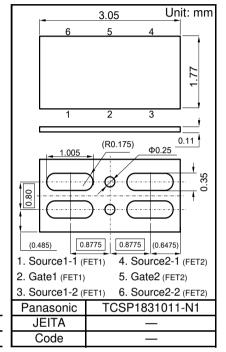
Packaging

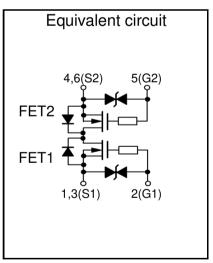
Embossed type (Thermo-compression sealing) : 1 000 pcs / reel (standard)

■ Absolute Maximum Ratings Ta = 25 °C							
Parameter	Symbol	Rating	Unit				
Source-source Voltage	VSS	20	V				
Gate-source Voltage	VGS	±12	V				
Source Current (DC) ^{*1}	IS	10	А				
Source Current (Pulsed) *1,*2	ISp	100	А				
Total Power Dissipation ^{*1}	PD	0.45	W				
Channel Temperature	Tch	150	°C				
Storage Temperature Range	Tstg	-55 to +150	°C				
Thermal Resistance (ch-a)	Rth(ch-a)	278	°C/W				

Note *1 Mounted on FR4 board ($25.4 \text{ mm} \times 25.4 \text{ mm} \times t1.0 \text{ mm}$) using the minimum recommended pad size ($36 \mu \text{m}$ Copper).

*2 t = 10 μ s, Duty Cycle \leq 1 %







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■ Electrical Characteristics Ta = 25 °C ± 3 °C

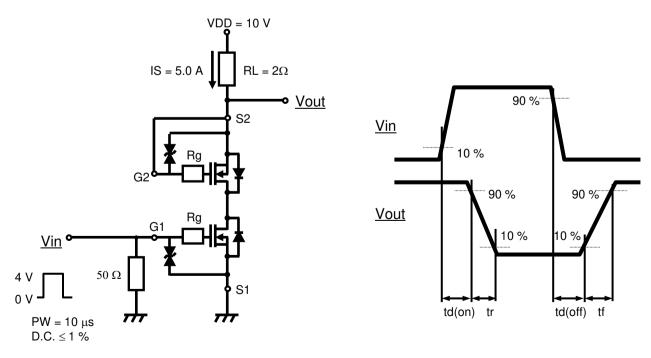
Parameter	Symbol	Conditions	Min	Тур	Max	Unit	
Source-source Breakdown Voltage	VSSS	IS = 1 mA, VGS = 0 V	20			V	
Zero Gate Voltage Source Current	ISSS	VSS = 20 V, VGS = 0 V			1.0	μA	
Gate-source Leakage Current	IGSS	$VGS = \pm 8 V, VSS = 0 V$			±10	μA	
Gate-source Threshold Voltage	Vth	VGS = ±5 V, VSS = 0 V IS = 1.41 mA, VSS = 10 V	0.35	0.90	±1.0 1.4	V	
Source-source On-state Resistance	RSS(on)1	IS = 5.0 A, VGS = 4.5 V	2.1	3.1	4.2	mΩ	
		IS = 5.0 A, VGS = 3.8 V	2.2	3.3	4.3		
	RSS(on)3	IS = 5.0 A, VGS = 3.1 V	2.4	3.8	6.0		
	RSS(on)4	IS = 5.0 A, VGS = 2.5 V	2.6	4.6	9.0		
Body Diode Forward Voltage	VF(s-s)	IF = 5.0 A, VGS = 0 V		0.8	1.2	V	
Input Capacitance ^{*1}	Ciss			3700		pF	
Output Capacitance ¹	Coss	VSS = 10 V, VGS = 0 V, f = 1 kHz		380			
Reverse Transfer Capacitance *1	Crss			340			
Turn-on delay Time ^{*1,*2}	td(on)	n) VDD = 10 V, VGS = 0 to 4.0 V		0.9		μS	
Rise Time ^{*1,*2}	tr	IS = 5.0 A	2.0		μ5		
Turn-off delay Time *1,*2	td(off)	VDD = 10 V, VGS = 4.0 to 0 V		6			
Fall Time ^{*1,*2}	tf	IS = 5.0 A		3.7		μS	
Total Gate Charge ^{*1}	Qg			33		nC	
Gate-source Charge ^{*1}	Qgs			11			
Gate-drain Charge ^{*1}	Qgd	IS = 5.0 A		9			
Gate Resistance ^{*1}	Rg	f = 1 kHz	400	700	1000	Ω	

Note Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

*1 Guaranteed by design, not subject to production testing

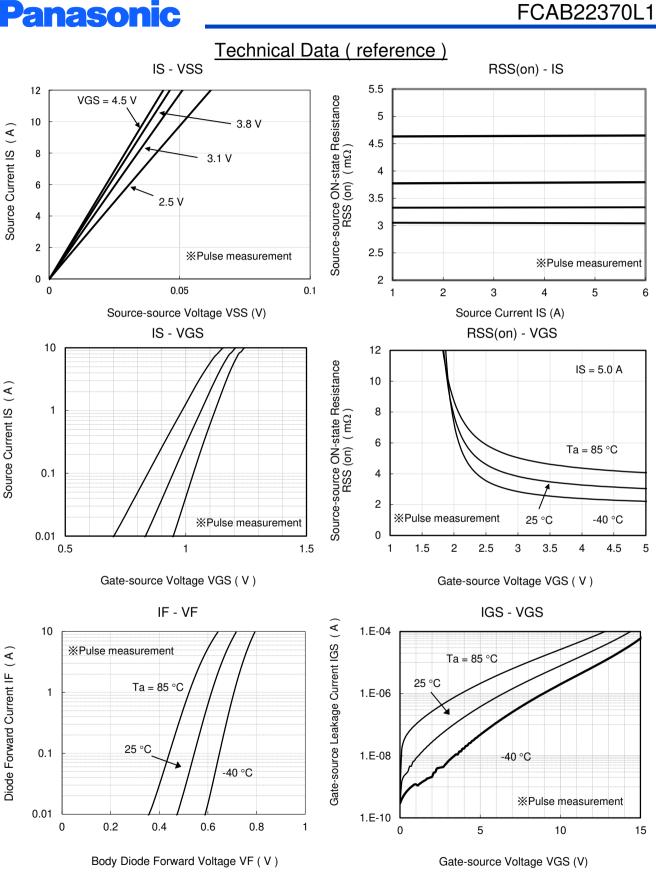
*2 Measurement circuit for Turn-on Delay Time / Rise Time / Turn-off Delay Time / Fall Time

Note2 : Measurement circuit



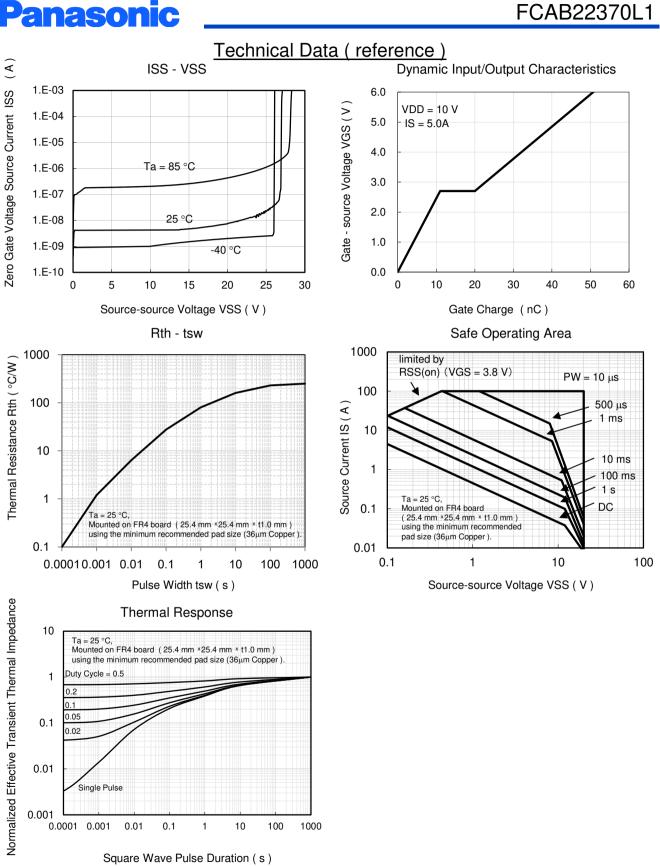
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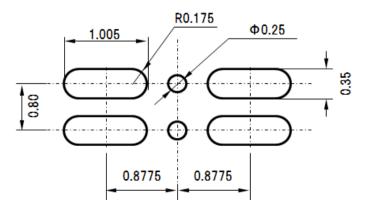
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 $\textbf{3.05} \pm 0.04$ 6 5 4 1.77 ± 0.04 Ο 3 1 2 0.11 -0.05 (R0.175) Φ0.25 1.005 0.35 Z 0.80 ·· _ · _ 0.8775 0.8775 (0.485) (0.6475)

■ Land Pattern (Reference)

Unit: mm

Established : 2015-10-23 :####-##-## Revised





■ Outline (TCSP1831011-N1)

Unit: mm

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